	Туре	L#	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	2	("20040232412").PN.	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:48
2	BRS	L10	15	7 and (mobility)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:57
3	IS&R	L2	3652	(257/13,79,94,101,102,103).CCLS.	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:50
4	BRS	L3	576	2 and (zno mgzno cdzno znas)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:51
5	BRS	L4	17	3 and (si silicon) adj wafer	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:52
6	BRS	L5	214	3 and (mqw ((multi multiple) near3 quantum near3 well))	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:54
7	BRS	L7	84	3 and (pn-junction 'pn junction')	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:55
8	BRS	L8	13	7 and ((dopant doping) adj concentration)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:56
9	BRS	L9	31	7 and (resistivity)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:57

	Type	L#	Hits	Search Text	DBs	Time Stamp
1	IS&R	L1	2	("20040232412").PN.	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:48
2	BRS	L10	15	7 and (mobility)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:59
3	BRS	L11	2	(nn junction 'nn junction')	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 16:05
4	BRS	L12	3	(mqw ((multi multiple) near3 quantum	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 16:07
5	BRS	L13	16	l .	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 16:24
6	IS&R	L2	3652	(257/13,79,94,101,102,103).CCLS.	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:50
7	BRS	L3	576	2 and (zno mgzno cdzno znas)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:51
8	BRS	L4	17	3 and (si silicon) adj wafer	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 16:24
9	BRS	L5	214	3 and (mqw ((multi multiple) near3 quantum near3 well))	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 16:07
10	BRS	L7	84	3 and (pn-junction 'pn junction')	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 16:04
11	BRS	L8	13	7 and ((dopant doping) adj concentration)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:59
12	BRS	L9	31	7 and (resistivity)	US-PGPUB; USPAT; EPO; DERWENT	2005/09/01 15:59